

Excellent Integrated System Limited

Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>ES3A-M3/9AT</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of ES3A-M3/9AT - DIODE GEN PURP 50V 3A DO214AB

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ES3A thru ES3D

Vishay General Semiconductor

HALOGEN

FREE



Surface Mount Ultrafast Plastic Rectifier



DO-214AB (SMC)

F	E	Δ	T	U	R	ES	

- · Glass passivated chip junction
- · Ideal for automated placement
- · Ultrafast recovery times for high efficiency
- Low forward voltage, low power losses
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Material categorization: For definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, and telecommunication.

MECHANICAL DATA

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test Polarity: Color band denotes cathode end

PRIMARY CHARACTERISTICS							
I _{F(AV)}	3.0 A						
V_{RRM}	50 V to 200 V						
I _{FSM}	100 A						
t _{rr}	20 ns						
V_{F}	0.90 V						
T _J max.	150 °C						

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MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		ES3A	ES3B	ES3C	ES3D	UNIT		
Device marking code		EA	EB	EC	ED			
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V		
Maximum RMS voltage	V _{RMS}	35	70	105	140	V		
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V		
Maximum average forward rectified current at T _L = 100 °C	I _{F(AV)}		3	.0		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	100				А		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C			

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	ES3A	ES3B	ES3C	ES3D	UNIT
Maximum instantaneous forward voltage	3.0 A		V _F ⁽¹⁾	0.90			٧	
Maximum DC reverse current at		T _A = 25 °C	I-		μΑ			
rated DC blocking voltage		T _A = 100 °C	· I _R	500				
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	20			ns	
Maximum reverse recovery time	$I_F = 3.0 \text{ A}, V_R = 30 \text{ V},$	$T_J = 25 ^{\circ}C$	+	30			- ns	
Maximum reverse recovery time	$dI/dt = 50 A/\mu s, I_{rr} = 10 \% I_{RM}$	T _J = 100 °C	t _{rr}	50				
Maximum stored charge	$I_F = 3.0 \text{ A}, V_R = 30 \text{ V},$	T _J = 25 °C	0	15			nC	
Maximum stored charge	$dI/dt = 50 A/\mu s$, $I_{rr} = 10 \% I_{RM}$	T _J = 100 °C	Q _{rr}	35				
Typical junction capacitance 4.0 V, 1 MHz			CJ	45			pF	

Note

 $^{^{(1)}}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER SYMBOL			ES3B	ES3C	ES3D	UNIT		
Typical thermal resistance	$R_{\theta JA}$ ⁽¹⁾	47						
Typical theimal resistance	R _{0JL} (1)	12				°C/W		

Note

⁽¹⁾ Units mounted on PCB with 0.31" x 0.31" (8.0 mm x 8.0 mm) copper pad areas

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
ES3D-M3/57T	0.211	57T	850	7" diameter plastic tape and reel				
ES3D-M3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

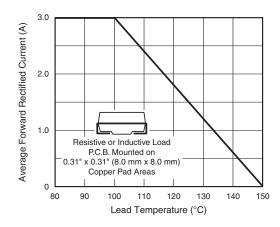


Fig. 1 - Maximum Forward Current Derating Curve

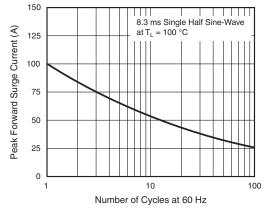


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

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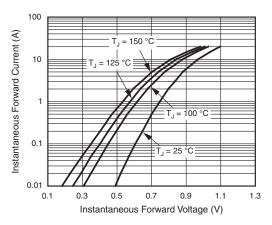


Fig. 3 - Typical Instantaneous Forward Characteristics

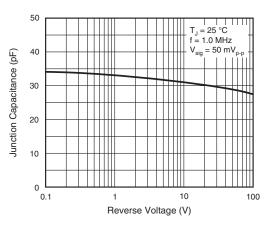


Fig. 5 - Typical Junction Capacitance

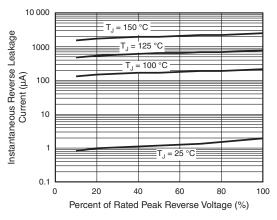
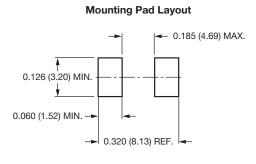


Fig. 4 - Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AB (SMC)

0.126 (3.20) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.012 (0.305) 0.006 (0.152) 0.006 (0.152) 0.008 (0.2) 0.008 (0.2) 0.008 (0.2) 0.008 (0.75)



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